



PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

Junichi KARASAWA et al.

Application No.: 10/807,288

Filed: March 24, 2004

Docket No.: 119222

For: FERROELECTRIC LAYER, METHOD OF MANUFACTURING FERROELECTRIC LAYER, FERROELECTRIC CAPACITOR, AND FERROELECTRIC MEMORY

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

Pursuant to 37 CFR §1.56, the attention of the Patent and Trademark Office is hereby directed to the reference listed on the attached PTO-1449. Unless otherwise indicated herein, one copy of each reference is attached. It is respectfully requested that the information be expressly considered during the prosecution of this application, and that the reference be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

- ☒ 1. This Information Disclosure Statement is being filed (a) within three months of the U.S. filing date of this non-CPA application, OR (b) before the mailing date of a first Office Action on the merits in the present application. No certification or fee is required.
- ☒ 2. Relevance of reference 1 is discussed in the present specification.

Respectfully submitted,

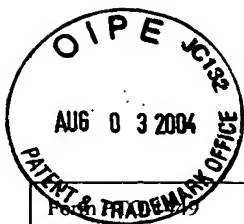
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119222APPLICATION NO.
10/807,288

INFORMATION DISCLOSURE STATEMENT

(Use several sheets if necessary)

APPLICANTS
Junichi KARASAWA et al.FILING DATE
March 24, 2004

U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS

FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB CLASS

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)

	1	Shimada et al., "High Density and Long Retention Non-Destructive Readout FeRAM Using a Linked Cell Architecture," Integrated Ferroelectrics, Vol. 40, pp. 41-54, 2001

EXAMINER

DATE CONSIDERED

Examiner: Initial if citation considered, whether or not citation is in conformance with M.P.E.P. 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

Date: August 3, 2004